International IOR Rectifier

HFA15PB60

$\mathsf{HEXFRED}^\mathsf{m}$

Ultrafast, Soft Recovery Diode

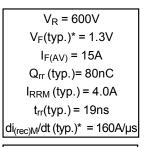
Features

- · Ultrafast Recovery
- · Ultrasoft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- · Specified at Operating Conditions

Benefits

- Reduced RFI and EMI
- · Reduced Power Loss in Diode and Switching Transistor
- · Higher Frequency Operation
- · Reduced Snubbing
- · Reduced Parts Count

BASE CATHODE





Description

International Rectifier's HFA15PB60 is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 15 amps continuous current, the HFA15PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_{b} portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA15PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

Absolute Maximum Ratings

	<u> </u>			
	Parameter	Max	Units	
V _R	Cathode-to-Anode Voltage	600	V	
I _F @ T _C = 100°C	Continuous Forward Current	15		
I _{FSM}	Single Pulse Forward Current	150	Α	
I _{FRM}	Maximum Repetitive Forward Current	60		
P _D @ T _C = 25°C	Maximum Power Dissipation	74	w	
P _D @ T _C = 100°C	Maximum Power Dissipation	29		
TJ	Operating Junction and	55 to 1450		
T _{STG}	Storage Temperature Range	-55 to +150	С	

^{* 125°}C

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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions	
V _{BR}	Cathode Anode Breakdown Voltage	600			V	I _R = 100μA	
V _{FM}	Max Forward Voltage		1.3	1.7	V	I _F = 15A	
			1.5	2.0		$I_F = 30A$ See Fig. 1	
			1.2	1.6		I _F = 15A, T _J = 125°C	
I _{RM}	Max Reverse Leakage Current		1.0	10	μA	$V_R = V_R$ Rated See Fig. 2	
			400	1000		$T_J = 125$ °C, $V_R = 0.8 \text{ x } V_R \text{ Rated}$	
CT	Junction Capacitance		25	50	pF	$V_R = 200V$ See Fig. 3	
L _S	Series Inductance		12		nΗ	Measured lead to lead 5mm from package body	

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min	Тур	Max	Units	Test Conditions	
t _{rr}	Reverse Recovery Time		19			$I_F = 1.0A$, $di_f/dt = 200$	A/μs, V _R = 30V
t _{rr1}	See Fig. 5, 10		42	60	ns	T _J = 25°C	
t _{rr2}			74	120		T _J = 125°C	I _F = 15A
I _{RRM1}	Peak Recovery Current		4.0	6.0	Α	T _J = 25°C	
I _{RRM2}	See Fig. 6		6.5	10	^	T _J = 125°C	$V_{R} = 200V$
Q _{rr1}	Reverse Recovery Charge		80	180	nC	T _J = 25°C	
Q _{rr2}	See Fig. 7		220	600	IIC	T _J = 125°C	$di_f/dt = 200A/\mu s$
di _{(rec)M} /dt1	Peak Rate of Fall of Recovery Current		188		A/µs	T _J = 25°C	
di _{(rec)M} /dt2	During t _b See Fig. 8		160		ΑνμS	T _J = 125°C	

Thermal - Mechanical Characteristics

	Parameter	Min	Тур	Max	Units
T _{lead} ①	Lead Temperature			300	°C
R _{thJC}	Thermal Resistance, Junction to Case			1.7	
R _{thJA} ②	Thermal Resistance, Junction to Ambient			40	K/W
R _{thCS} 3	Thermal Resistance, Case to Heat Sink		0.25		
Wt	Weight		6.0		g
			0.21		(oz)
	Mounting Torque	6.0		12	Kg-cm
	Mounting Torque	5.0		10	lbf•in

 $\, \oplus \,$ 0.063 in. from Case (1.6mm) for 10 sec

② Typical Socket Mount

③ Mounting Surface, Flat, Smooth and Greased

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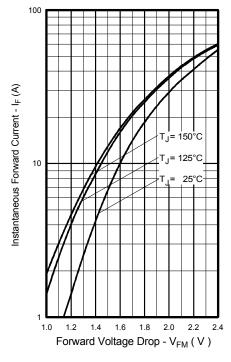


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

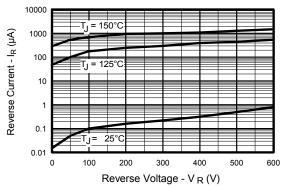


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

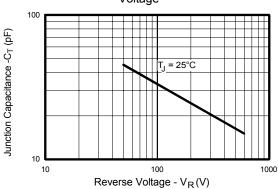
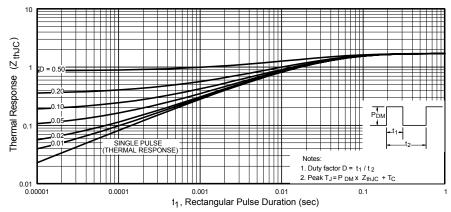


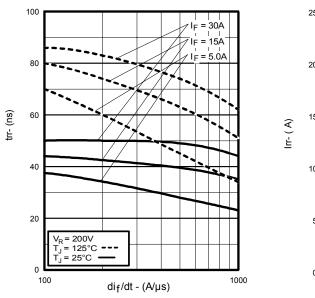
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



 $\textbf{Fig. 4} - \text{Maximum Thermal Impedance Z_{thjc} Characteristics}$

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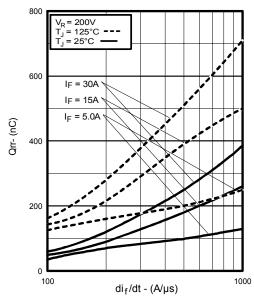
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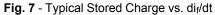


25 V_R = 200V T_J = 125°C ---T_J = 25°C ---15 I_F = 30A I_F = 15A I_F = 5.0A 100 di f/dt - (A/μs)

Fig. 5 - Typical Reverse Recovery Time vs. dif/dt

Fig. 6 - Typical Recovery Current vs. dif/dt





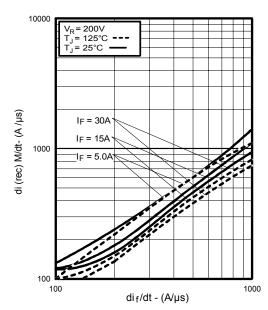


Fig. 8 - Typical $di_{(rec)M}/dt$ vs. di_f/dt

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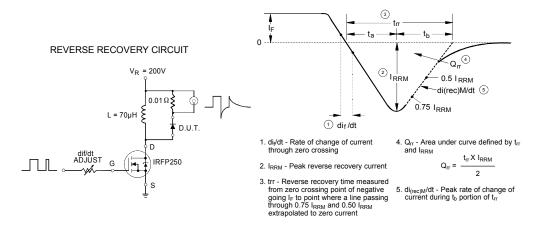
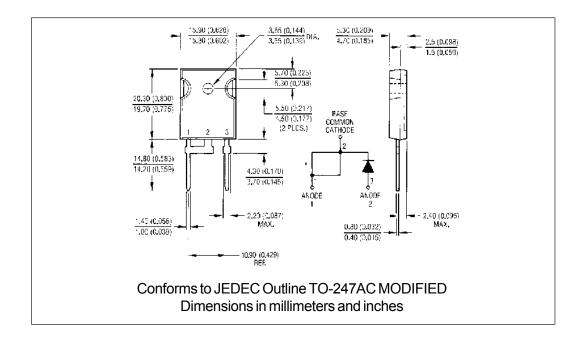


Fig. 9 - Reverse Recovery Parameter Test Circuit

Fig. 10 - Reverse Recovery Waveform and Definitions

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International **Rectifier**

WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332. EUROPEAN HEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408. IR CANADA: 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801. IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933. IR ITALY: Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 45101111. Fax: ++ 39 11 4510220. IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086. IR SOUTHEAST ASIA: 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630. IR TAIWAN: 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

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